

# Abstracts

## On the Pressure Dependence of Microwave Crystal Rectifiers (Correspondence)

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*W.G. Matthei. "On the Pressure Dependence of Microwave Crystal Rectifiers (Correspondence)." 1958 Transactions on Microwave Theory and Techniques 6.1 (Jan. 1958 [T-MTT]): 112-112.*

During the past couple of years, as a result of government interest, silicon microwave crystal rectifiers have not only decreased their noise figures but also have increased their resistance to adverse environments; i.e., high burnout, high temperature, excessive humidity.

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